

2SB1275

PNP -1.5A -160V Middle Power Transistor

Parameter	Value
V <sub>CEO</sub>	-160V
Ι <sub>C</sub>	-1.5A

#### Features

- 1) Suitable for Middle Power Driver
- 2) Complementary NPN Types: 2SD1918
- 3) High voltage :  $V_{CEO} = -160V$
- 4) Lead Free/RoHS Compliant.

#### Outline





### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SB1275	CPT3	6595	TL	330	16	2,500	B1275

#### •Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V <sub>CBO</sub>	-160	V
Collector-emitter voltage		V <sub>CEO</sub>	-160	V
Emitter-base voltage		V <sub>EBO</sub>	-5	V
Collector current	DC	۱ <sub>C</sub>	-1.5	А
	Pulsed	ا <sub>CP</sub> *1	-3.0	А
Power dissipation		P <sub>D</sub> <sup>*2</sup>	1	W
		P <sub>D</sub> <sup>*3</sup>	10	W
Junction temperature		T <sub>j</sub>	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to +150	°C

\*1 Pw=100ms , single pulse

\*2 Mounted on a substrate

\*3 Tc=25°C

### •Electrical characteristics(Ta = 25°C)

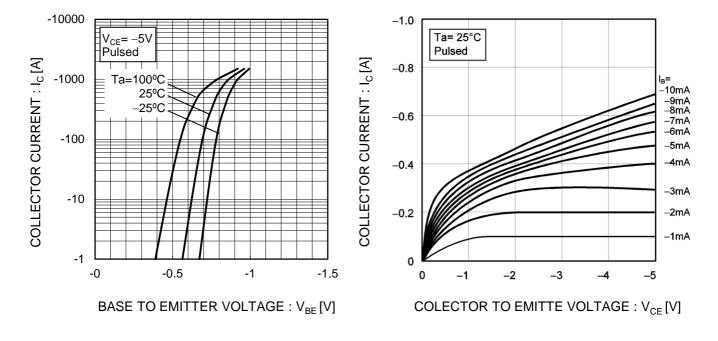
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	$BV_{CEO}$	$I_{C} = -1mA$	-160	-	-	V
Collector-base breakdown voltage	$BV_{CBO}$	Ι <sub>C</sub> = -50μΑ	-160	-	-	V
Emitter-base breakdown voltage	$BV_{EBO}$	Ι <sub>E</sub> = -50μΑ	-5	-	-	V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = -120V	-	-	-1	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -4V$	-	-	-1	μA
Collector-emitter saturation voltage	V <sub>CE(sat)</sub> *4	$I_{\rm C} = -1A, \ I_{\rm B} = -0.1A$	-	-	-2	V
DC current gain	h <sub>FE</sub>	$V_{CE} = -5V, I_{C} = -100mA$	82	-	180	-
Transition frequency	f⊤	$V_{CE} = -5V, I_E = 100mA$ f=30MH <sub>Z</sub>	-	50	-	MHz
Output capacitance	C <sub>ob</sub>	$V_{CB} = -10V, I_E = 0A,$ f = 1MHz	-	30	-	pF

\*4 Pulsed

### ●h<sub>FE</sub> rank categories

Rank	Р
h <sub>FE</sub>	82 to 180

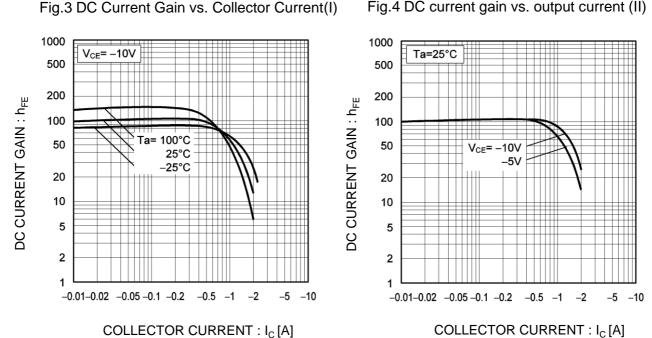
#### •Electrical characteristic curves(Ta = 25°C)



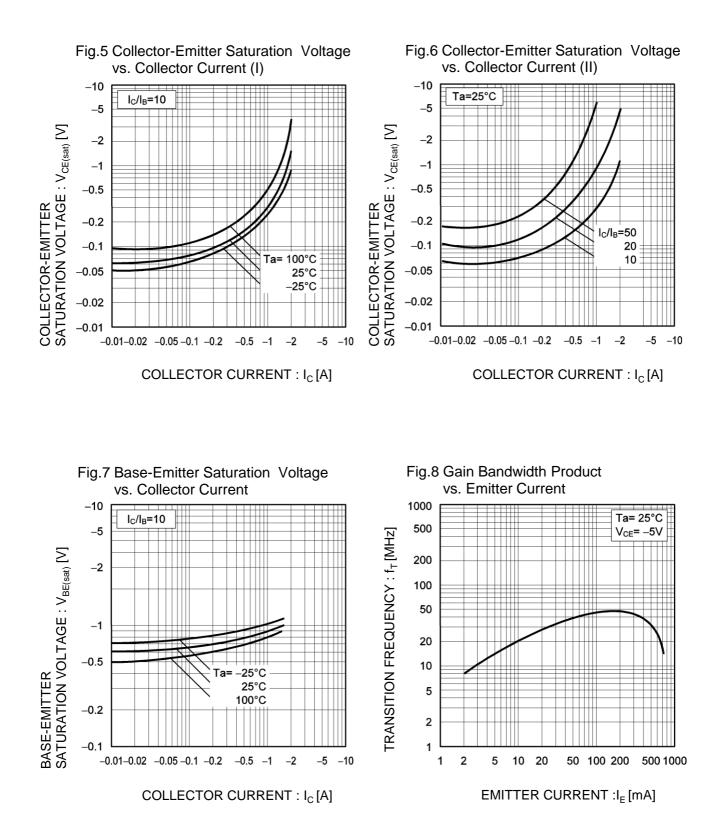
#### Fig.1 Ground Emitter Propagation Characteristics

Fig.4 DC current gain vs. output current (II)

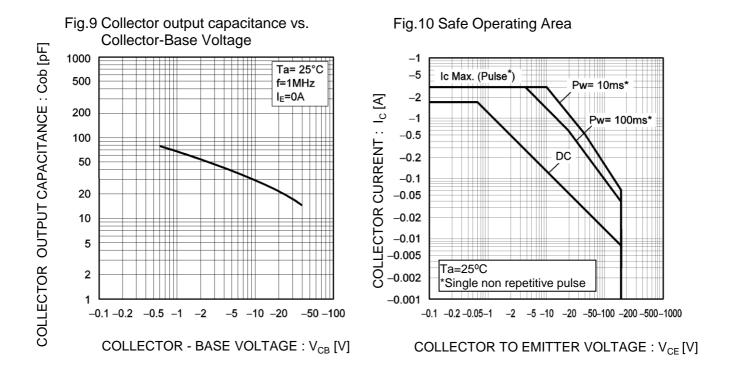
Fig.2 Typical Output Characteristics



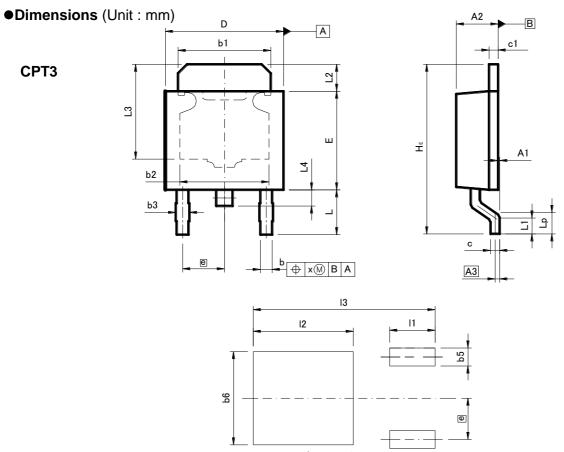
#### •Electrical characteristic curves(Ta = 25°C)



#### ●Electrical characteristic curves(Ta = 25°C)







Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INC	HES	
DIM	MIN	MAX	MIN	MAX	
A1	0.00	0.15	0.000	0.006	
A2	2.20	2.50	0.087	0.098	
A3	0.1	25	0.010		
b	0.55	0.75	0.022	0.030	
b1	5.00	5.30	0.197	0.209	
b2	5.	00	0.1	97	
b3	0.	75	0.0		
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.30	6.70	0.248	0.264	
E	5.40	5.80	0.213	0.228	
е	2.5	30	0.0	91	
HE	9.00	10.00	0.354	0.394	
L	2.20	2.80	0.087	0.110	
L1	0.80	1.40	0.031	0.055	
L2	1.20	1.80	0.047	0.071	
L3	5.	30	0.2	09	
L4	0.90		0.0	35	
Lp	1.00	1.60	0.039	0.063	
х	_	0.25	-	0.010	

DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
b5	-	1.00	-	0.04	
b6	-	5.20	-	0.205	
11	-	2.50	-	0.098	
12	-	5.50	-	0.217	
13	-	10.00	-	0.394	

Dimension in mm / inches

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## 2SB1275 - Web Page

**Distribution Inventory** 

Part Number	2SB1275
Package	CPT3
Unit Quantity	2500
Minimum Package Quantity	2500
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes

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